MP2333H



4.2 - 18V Input, 3A, 1.2MHz Synchronous Buck Converter with Power Good and Soft Start in SOT583 (1.6x2mm) Package

DESCRIPTION

The MP2333H is a fully integrated, high-frequency, synchronous, rectified, step-down, switch-mode converter with internal power MOSFETs. The MP2333H offers a very compact solution that achieves 3A of continuous output current with excellent load and line regulation over a wide input range. The MP2333H uses synchronous mode operation for higher efficiency over the output current load range.

Constant-on-time (COT) control operation provides very fast transient response, easy loop design, and very tight output regulation.

Full protection features include short-circuit protection (SCP), over-current protection (OCP), under-voltage protection (UVP), and thermal shutdown.

The MP2333H requires a minimal number of readily available, standard, external components and is available in a space-saving SOT583 package

FEATURES

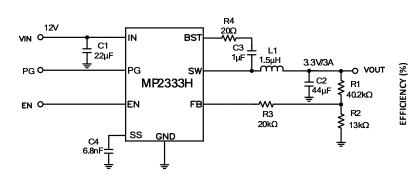
- Wide 4.2V to 18V Operating Input Range
- 75mΩ/40mΩ Low R_{DS(ON)} Internal Power MOSFETs
- 200µA Low I_Q
- High-Efficiency Synchronous Mode Operation
- Fast Load Transient Response
- 1.2MHz Switching Frequency
- Ton Extension
- Forced PWM Operation
- Programmable Soft-Start Time
- Power Good (PG) Indication
- Over-Current Protection (OCP) and Hiccup
- Pre-Bias Start-Up
- Thermal Shutdown
- Available in a SOT583 (1.6mmx2.0mm) Package

APPLICATIONS

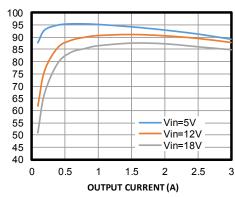
- Game Consoles
- Digital Set-Top Boxes
- Flat-Panel Television and Monitors
- General Consumer Purposes

All MPS parts are lead-free, halogen-free, and adhere to the RoHS directive. For MPS green status, please visit the MPS website under Quality Assurance. "MPS", the MPS logo, and "Simple, Easy Solutions" are trademarks of Monolithic Power Systems, Inc. or its subsidiaries.

TYPICAL APPLICATION



Efficiency Vout = 3.3V, L = 1.5μ H, DCR = 4.3m Ω





ORDERING INFORMATION

Part Number*	Package	Top Marking
MP2333HGTL	SOT583 (1.6mmx2.0mm)	See Below

^{*} For Tape & Reel, add suffix -Z (e.g.: MP2333HGTL-Z).

TOP MARKING

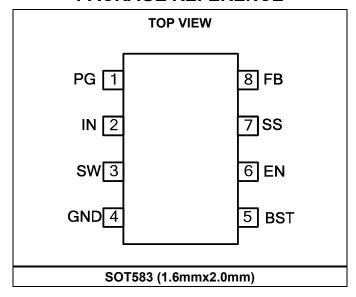
BCJY

LLL

BCJ: Product code of MP2333HGTL

Y: Year code LLL: Lot number

PACKAGE REFERENCE





PIN FUNCTIONS

Package Pin #	Name	Description
1	PG	Power good output. The output of PG is an open drain. Decouple PG with a 1nF capacitor.
2	IN	Supply voltage. The MP2333H operates from a 4.2V to 18V input rail. A capacitor (C1) is required to decouple the input rail. Connect IN using a wide PCB trace.
3	SW	Switch output. Connect SW using a wide PCB trace.
4	GND	System ground. GND is the reference ground of the regulated output voltage and requires extra care during the PCB layout. Connect GND with copper traces and vias.
5	BST	Bootstrap. Connect a 1µF BST capacitor and a resistor between SW and BST to form a floating supply across the high-side switch driver.
6	EN	Enable. Drive EN high to enable the MP2333H. For automatic start-up, connect EN to V_{IN} through a $604\text{k}\Omega$ pull-up resistor.
7	SS	Soft start. Connect an external capacitor to SS to program the soft-start time for the switch-mode regulator.
8	FB	Feedback. Connect FB to the tap of an external resistor divider from the output to GND to set the output voltage.

ABSOLUTE MAXIMUM RATINGS (1)

V _{IN}	0.3V to 20V
V_{SW} 0.3V (-6.5V for <10ns	, -0.6V for <2µs)
to 20V	(21V for <10ns)
V _{BST}	V _{SW} + 5V
V _{EN}	0.3V to 5V (2)
All other pins	0.3V to 4V
Continuous power dissipation (T	$_{A} = +25^{\circ}C)^{(3)(5)}$
	2.2W
Junction temperature	150°C
Lead temperature	260°C
Storage temperature	65°C to 150°C

Recommended Operating Conditions (4)

Supply voltage (V _{IN})	4.2V to 18V
Output voltage (Vout)	0.8V to 0.9 * V _{IN}
	or 13\/ may

Operating junction temp. (T_J)....-40°C to +125°C

Thermal Resistance

SOT583 (1.6mmx2.0mm)	$oldsymbol{ heta}_{JA}$	$oldsymbol{ heta}_{JC}$	
EV2333H-TL-00A (5)	55	21	°C/W
JESD51-7 ⁽⁶⁾	130	60	°C/W

NOTES:

- 1) Exceeding these ratings may damage the device.
- For details on EN's ABS max rating, refer to the Enable Control section on page 12.
- 3) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-toambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation on EV2333H Board at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 5) Measured on EV2333H-TL-00A, 2-layer PCB, 64mmx48mm.
- 6) The value of θ_{JA} given in this table is only valid for comparison with other packages and cannot be used for design purposes. These values were calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.



ELECTRICAL CHARACTERISTICS

 V_{IN} = 12V, T_J = -40°C to +125°C ⁽⁷⁾, typical value is tested at T_J = +25°C, unless otherwise noted.

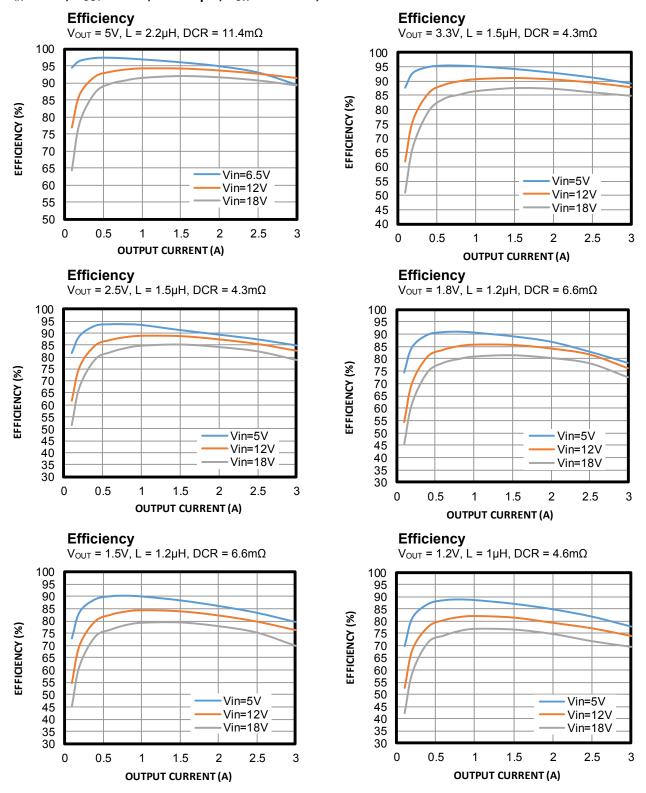
Parameter	Symbol	Condition	Min	Тур	Max	Units
Supply current (shutdown)	I _{IN}	$V_{EN} = 0V$			10	μA
Supply current (quiescent)	lα	$V_{EN} = 2V, V_{FB} = 0.85V$		200		μA
HS switch on resistance	HS _{RDS(ON)}	V _{BST - SW} = 3.3V		75		mΩ
LS switch on resistance	LS _{RDS(ON)}			40		mΩ
Switch leakage	SWLKG	V _{EN} = 0V			1	μΑ
Low-side switching current limit OCP	ILIMIT_LS_OC		2.8	4		Α
Negative current limit (8)	I _{NC}	V _{OUT} = 3.3V, L = 1.5μH		-1.3		mA
Oscillator frequency	fsw	V _{FB} = 0.75V	960	1200	1440	kHz
Minimum on time (8)	TON_MIN			45		ns
Minimum off time (8)	TOFF_MIN			190		ns
Feedback voltage	V_{REF}		789	805	821	mV
Feedback current	I _{FB}			10	80	nA
Hiccup duty cycle (8)				25		%
EN rising threshold	V _{EN_RISING}		1.16	1.23	1.29	V
EN hysteresis	V _{EN_HYS}			100		mV
ENI in and an annual		V _{EN} = 2V		2		μА
EN input current	I _{EN}	V _{EN} = 0V		0		
V _{IN} under-voltage lockout threshold rising	INUVVth			4		V
V _{IN} under-voltage lockout threshold hysteresis	INUVHYS			400		mV
Power good rising threshold UV	PG _{UV_R}		87	92	97	$%V_{REF}$
Power good falling threshold UV	PG _{UV_F}		82	87	92	%V _{REF}
Power good rising threshold OV	PG _{ov_R}		115	120	125	%V _{REF}
Power good falling threshold OV	PG_{OV_F}		102	107	112	%V _{REF}
Power good rising delay				50		μs
Power good falling delay				35		μs
Power good sink current capability	V _{PG}	Sink 1mA		0.13	0.4	V
Power good leakage current	I _{PG_LEK}				3	μΑ
Soft-start current	Iss		5.3	7.3	9.3	μΑ
Thermal shutdown (8)				150		°C
Thermal hysteresis (8)				20		°C

⁷⁾ Not tested in production. Guaranteed by over-temperature correlation. 8) Guaranteed by design and engineering sample characterization.



ELECTRICAL CHARACTERISTICS

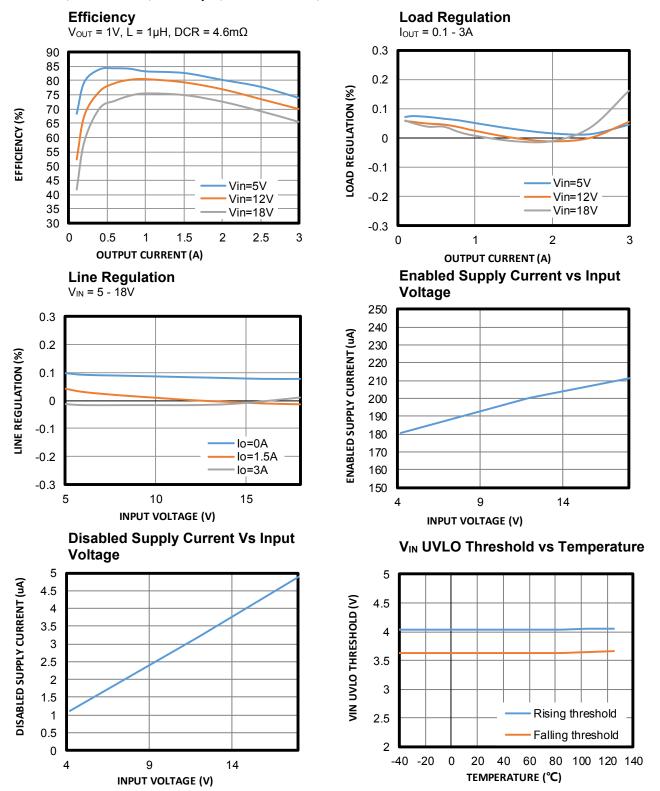
 V_{IN} = 12V, V_{OUT} = 3.3V, L = 1.5 μ H, F_{SW} = 1.2MHz, unless otherwise noted.





ELECTRICAL CHARACTERISTICS (continued)

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 1.5 μ H, F_{SW} = 1.2MHz, unless otherwise noted.

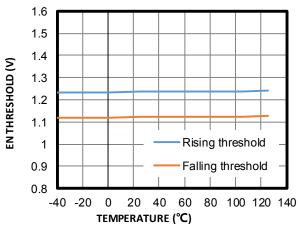




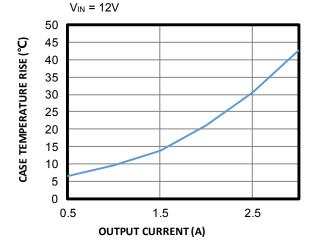
ELECTRICAL CHARACTERISTICS (continued)

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 1.5 μ H, F_{SW} = 1.2MHz, unless otherwise noted.

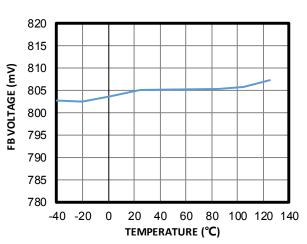
EN Threshold vs Temperature



Case Temperature Rise vs Output Current

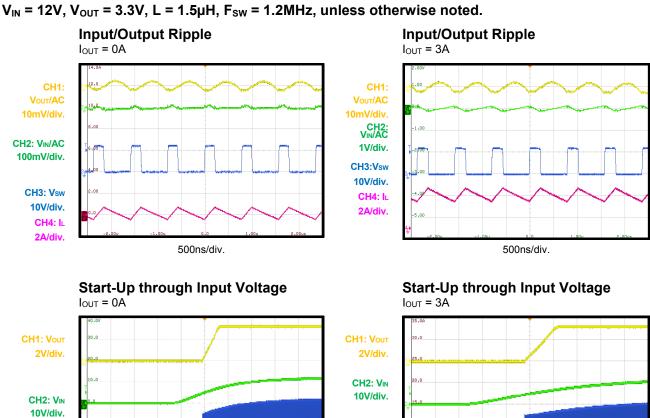


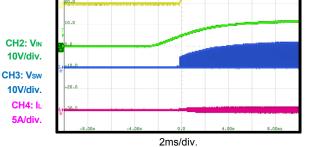
FB Voltage vs Temperature

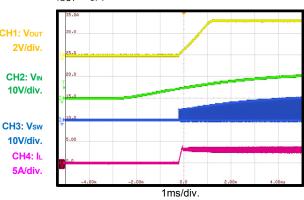


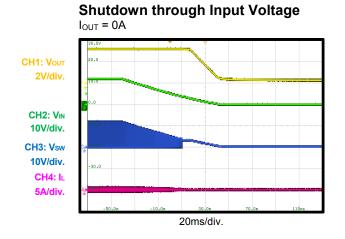


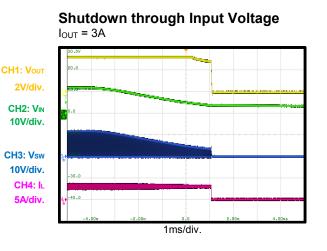
TYPICAL PERFORMANCE CHARACTERISTICS







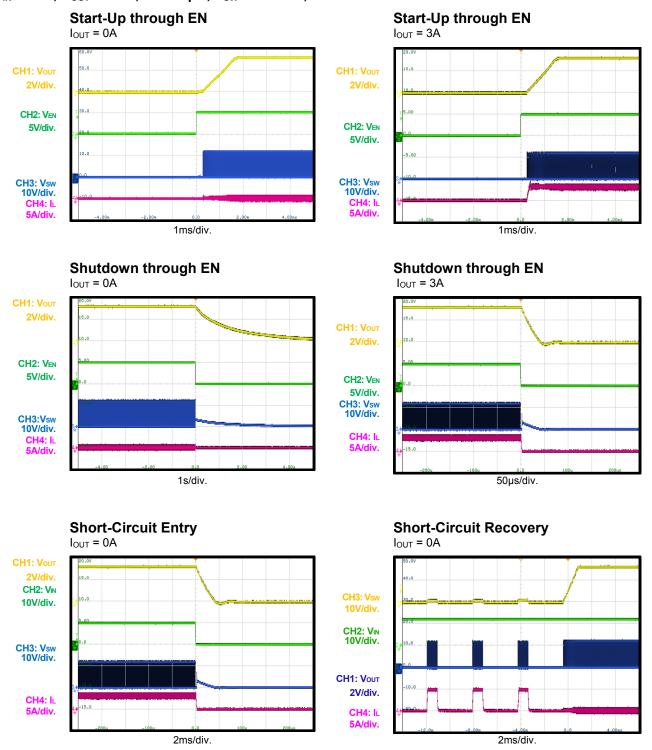






TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 1.5 μ H, F_{SW} = 1.2MHz, unless otherwise noted.



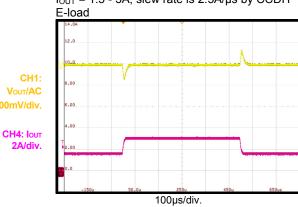


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 1.5 μ H, F_{SW} = 1.2MHz, unless otherwise noted.

Load Transient





100mV/div.



BLOCK DIAGRAM

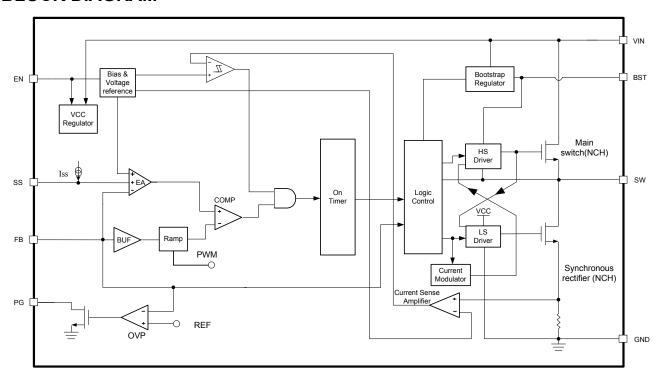


Figure 1: Functional Block Diagram



OPERATION

The MP2333H is a fully integrated, synchronous, rectified, step-down, switch-mode converter. Constant-on-time (COT) control is employed to provide fast transient response and easy loop stabilization.

At the beginning of each cycle, the high-side MOSFET (HS-FET) is turned on when the FB voltage (V_{RB}) drops below the reference voltage (V_{REF}). The HS-FET is turned on for a fixed interval determined by the one-shot on-timer. The on-timer is determined by both the output voltage and input voltage to make the switching frequency fairly constant over the input voltage range. After the on period elapses, the HS-FET is turned off until the next period begins. By repeating this operation, the converter regulates the output voltage.

The MP2333H operates in forced continuous conduction mode (CCM). The low-side MOSFET (LS-FET) is turned on when the HS-FET is in its off state to minimize conduction loss. There is a dead short between the input and GND if both the HS-FET and LS-FET are turned on at the same time. This is called shoot-through. To prevent shoot-through, a dead time is generated internally between the HS-FET off and LS-FET on period, or the LS-FET off and HS-FET on period.

Enable Control (EN)

EN is a digital control pin that turns the regulator on and off. Drive EN high to turn on the regulator, drive EN low to turn off the regulator. EN is clamped internally using a 2.8V series Zener diode (see Figure 2). Connecting the EN input through a pull-up resistor to V_{IN} limits the EN input current below 40μA to prevent damage to the Zener diode. For example, when connecting a $604k\Omega$ pull-up resistor to $12V\ V_{IN}$, I_{Zener} = (12V-2.8V) / $(604k\Omega+35k\Omega)$ = 14μ A.

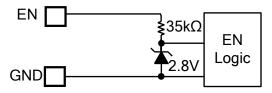


Figure 2: Zener Diode between EN and GND

Under-Voltage Lockout (UVLO)

Under-voltage lockout (UVLO) protects the chip from operating at an insufficient supply voltage. The MP2333H UVLO comparator monitors the output voltage of the internal regulator (VCC). The UVLO rising threshold is about 4V, while its falling threshold is 3.6V.

Soft Start (SS)

The MP2333H employs a soft start (SS) mechanism to ensure smooth output ramping during power-up. When the MP2333H starts up, an internal current source (typically 7.3 μ A) charges up the SS capacitor to generate a soft-start voltage (Vss). When Vss/2 is below VREF, Vss/2 overrides VREF. The error amplifier (EA) uses Vss/2 as the reference. The output voltage ramps up smoothly. Once Vss/2 rises above the VREF, the EA uses VREF as the reference. At this point, the soft start finishes, and the MP2333H enters steady-state operation.

The SS capacitor value can be determined with Equation (1):

$$C_{ss}(nF) = \frac{T_{ss}(ms) \times I_{ss}(uA)}{2V_{RFF}}$$
 (1)

Over-Current Protection (OCP) and Short-Circuit Protection (SCP)

The MP2333H has a valley-limit control. The inductor current is monitored during the LS-FET on state. When the sensed inductor current reaches the valley current limit, the LS limit comparator turns over, and the MP2333H enters over-current protection (OCP) mode, the HS-FET waits until the valley current limit is removed before turning on again. Meanwhile, the output voltage drops until V_{FB} is below the under-voltage (UV) threshold. Once UV is triggered, the MP2333H enters hiccup mode to restart the part periodically.

In OCP, the device attempts to recover from the over-current (OC) fault with hiccup mode. In hiccup mode, the chip disables the output power stage, discharges the soft start, and attempts to soft start again automatically. If the OC condition still remains after the soft start ends, the device repeats this operation cycle until the OC condition is removed and the output rises back to the regulation level. OCP is a non-latch protection.



Power Good (PG)

Power good (PG) indicates whether the output voltage is in the normal range or not compared to the internal reference voltage. PG is an open-drain structure and requires an external pull-up supply. During power-up, the power good output is pulled low. This indicates to the system to remain off and keep the load on the output to a minimum. This helps reduce inrush current during start-up.

When the output voltage is higher than 92% and lower than 120% of the internal reference voltage and the soft start is finished, the power good signal is pulled high. When the output voltage is lower than 87% after the soft start finishes, the PG signal remains low. When the output voltage is higher than 120% of the internal reference, PG is switched low. The PG signal rises high again after the output voltage drops below 107% of the internal reference voltage.

The PG output is pulled low when EN is low, V_{IN} is low, or OCP or over-temperature protection (OTP) is triggered.

Pre-Bias Start-Up

The MP2333H is designed for monotonic start-up into pre-biased loads. If the output is pre-biased to a certain voltage during start-up, the BST voltage is refreshed and charged, and the voltage on the soft start is charged as well. If the BST voltage exceeds its rising threshold voltage, and $V_{\rm SS}/2$ exceeds the sensed output voltage at FB, the part begins working normally.

TON Extension Operation

To improve dropout, the MP2333H is designed to extend the on time when the minimum off time is reached. The HS-FET on time extends, and the frequency drops. The typical minimum frequency is 280kHz. When the frequency drops to 280kHz, the frequency cannot reduce further, and the duty cycle reaches the max duty cycle (Dmax). If the input voltage continues to drop, the MP2333H works at the max duty cycle, and the output voltage drops. The typical Dmax is 95%.

Thermal Shutdown

Thermal shutdown prevents the chip from operating at exceedingly high temperatures. When the silicon die temperature exceeds 150°C, the entire chip shuts down. When the temperature falls below its lower threshold (typically 130°C), the chip is enabled again.

Floating Driver and Bootstrap Charging

An external bootstrap capacitor powers the floating power MOSFET driver. This floating driver has its own UVLO protection with a rising threshold of 2.2V and a hysteresis of 150mV. $V_{\rm IN}$ regulates the bootstrap capacitor voltage internally through D1, M1, R4, C3, L1, and C2 (see Figure 3). If $V_{\rm IN}$ - $V_{\rm SW}$ exceeds 3.3V, U2 regulates M1 to maintain a 3.3V BST voltage across C3.

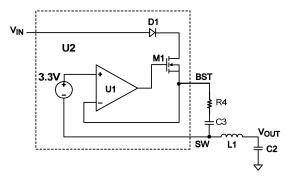


Figure 3: Internal Bootstrap Charger

Start-Up and Shutdown

If both V_{IN} and EN exceed their respective thresholds, the chip starts up. The reference block starts first, generating a stable reference voltage and current, and then the internal regulator is enabled. The regulator provides a stable supply for the remaining circuits.

Three events can shut down the chip: EN low, V_{IN} low, and thermal shutdown. The shutdown procedure starts by blocking the signaling path initially to avoid any fault triggering. The internal supply rail is then pulled down.



APPLICATION INFORMATION

Setting the Output Voltage

An external resistor divider is used to set the output voltage. First, choose a value for R2. R2 should be chosen reasonably, since a small R2 leads to considerable quiescent current loss, but a large R2 makes FB noise-sensitive. Typically, an R2 value between 5 - 30µA provides a good balance between system stability and no-load loss. Then determine R1 with Equation (2):

$$R1 = \frac{V_{OUT} - V_{REF}}{V_{REF}} \times R2$$
 (2)

The feedback circuit is shown in Figure 4.

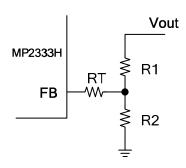


Figure 4: Feedback Network

Table 1 and Table 2 list the recommended parameters for common output voltages.

Table 1: Parameter Selection for Common Output Voltages, V_{IN} = 12V⁽⁹⁾

Vout (V)	R1 (kΩ)	R2 (kΩ)	RT (kΩ)	L (µH)
1.0	33	133	30	1
1.2	40.2	82	30	1
1.5	40.2	45.3	30	1.2
1.8	40.2	32.4	20	1.2
2.5	40.2	19.1	20	1.5
3.3	40.2	13	20	1.5
5	40.2	7.68	10	2.2

NOTE:

9) Different output inductor values and output capacitor values may affect the selection of R1, R2, and RT. For additional component parameters, refer to the Typical Application Circuits on page 17 to page 19.

Table 2: Parameter Selection for Common Output Voltages, V_{IN} = 5V

V _{OUT} (V)	R1 (kΩ)	R2 (kΩ)	RT (kΩ)	L (µH)
1.0	33	133	30	0.47
1.2	40.2	82	30	0.68
1.5	40.2	45.3	30	0.68
1.8	40.2	32.4	20	0.68
2.5	40.2	19.1	20	0.68
3.3	40.2	13	40.2	0.47
5 (10)	40.2	7.68	10	0.68

NOTE:

10) For $V_{OUT} = 5V$, V_{IN} should be no lower than 6.5V.

Selecting the Inductor

An inductor is necessary for supplying constant current to the output load while being driven by the switched input voltage. A larger-value inductor results in less ripple current and a lower output ripple voltage but also has a larger physical footprint, higher series resistance, and lower saturation current. A good rule for determining the inductance value is to design the peak-to-peak ripple current in the inductor to be in the range of 30 - 60% of the maximum output current. The peak inductor current should be below the maximum switch current limit. The inductance value can be calculated with Equation (3):

$$L = \frac{V_{OUT}}{F_{SW} \times \Delta I_{L}} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
 (3)

Where ΔI_{L} is the peak-to-peak inductor ripple current.

The inductor should not saturate under the maximum inductor peak current, where the peak inductor current can be calculated with Equation (4):

$$I_{LP} = I_{OUT} + \frac{V_{OUT}}{2F_{SW} \times L} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
 (4)

Selecting the Input Capacitor

The input current to the step-down converter is discontinuous and therefore requires a capacitor to supply AC current to the step-down converter while maintaining the DC input voltage. For the best performance, use ceramic capacitors placed as close to IN as possible. Capacitors with X5R and X7R ceramic dielectrics are recommended because they are fairly stable with temperature fluctuations.



The capacitors must also have a ripple current rating greater than the maximum input ripple current of the converter. The input ripple current can be estimated with Equation (5):

$$I_{CIN} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})}$$
 (5)

The worst-case condition occurs at $V_{IN} = 2V_{OUT}$, shown in Equation (6):

$$I_{CIN} = \frac{I_{OUT}}{2} \tag{6}$$

For simplification, choose an input capacitor with an RMS current rating greater than half of the maximum load current.

The input capacitance value determines the input voltage ripple of the converter. If there is an input voltage ripple requirement in the system, choose an input capacitor that meets the specification.

The input voltage ripple can be estimated with Equation (7):

$$\Delta V_{IN} = \frac{I_{OUT}}{F_{SW} \times C_{IN}} \times \frac{V_{OUT}}{V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
 (7)

The worst-case scenario occurs at $V_{IN} = 2V_{OUT}$, shown in Equation (8):

$$\Delta V_{IN} = \frac{1}{4} \times \frac{I_{OUT}}{F_{SW} \times C_{IN}}$$
 (8)

Selecting the Output Capacitor

An output capacitor is required to maintain the DC output voltage. Ceramic or POSCAP capacitors are recommended. The output voltage ripple can be estimated with Equation

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{F_{\text{SW}} \times L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \times (R_{\text{ESR}} + \frac{1}{8 \times F_{\text{SW}} \times C_{\text{OUT}}}) \quad (9)$$

In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is caused mainly by the capacitance.

For simplification, the output voltage ripple can be estimated with Equation (10):

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{8 \times F_{\text{SW}}^2 \times L \times C_{\text{OUT}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \quad (10)$$

The output voltage ripple caused by the ESR is very small. In the case of POSCAP capacitors, the ESR dominates the impedance at the switching frequency. For simplification, the output ripple can be approximated with Equation (11):

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{F_{\text{SW}} \times L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \times R_{\text{ESR}} \quad (11)$$

Choose a larger output capacitor for a better load transient response, but be sure to consider the maximum output capacitor limitation in the design application. If the output capacitor value is too high, the output voltage cannot reach the design value during the soft-start time and will fail to regulate. The maximum output capacitor value (C_{o max}) can be limited approximately with Equation (12):

$$C_{\text{O} \text{MAX}} = (I_{\text{LIM} \text{AVG}} - I_{\text{OUT}}) \times T_{\text{ss}} / V_{\text{OUT}} \quad (12)$$

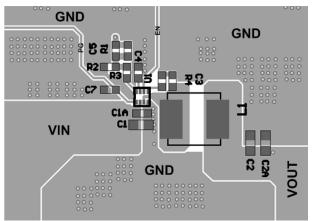
Where I_{LIM AVG} is the average start-up current during the soft-start period, and T_{ss} is the softstart time.

PCB Layout Guidelines

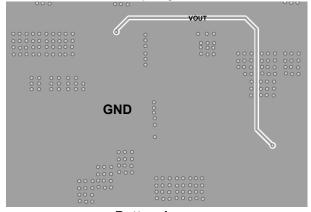
Efficient PCB layout of the switching power supplies is critical for stable operation. A poor layout design can result in poor line or load regulation and stability issues. For best results, refer to Figure 5 and follow the guidelines below.

- 1. Place the high-current paths (GND, VIN, and SW) as close to the device as possible with short, direct, and wide traces.
- 2. Place the input capacitor as close to IN and GND as possible (recommended within 1mm).
- 3. Place the external feedback resistors next
- 4. Keep the switching node (SW) short and away from the feedback network.









Bottom Layer Figure 5: Recommended Layout

Design Example

Table 3 shows a design example when ceramic capacitors are applied.

Table 3: Design Example

V _{IN}	12V
Vout	3.3V
Іоит	3A

The detailed application schematics are shown in Figure 6 through Figure 12. The typical performance and waveforms are shown in the Typical Characteristics section. For more devices applications, please refer to the related evaluation board datasheet.



TYPICAL APPLICATION CIRCUITS

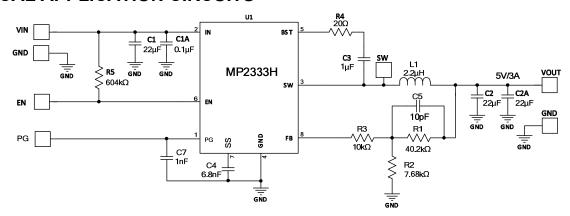


Figure 6: V_{IN} = 12V, V_{OUT} = 5V/3A

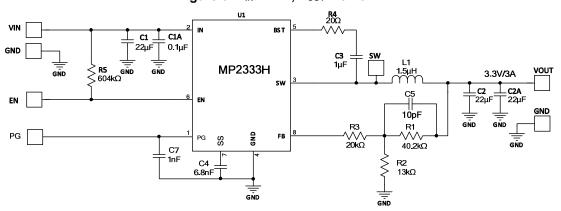


Figure 7: $V_{IN} = 12V$, $V_{OUT} = 3.3V/3A$

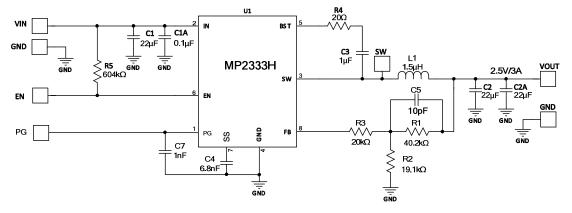


Figure 8: $V_{IN} = 12V$, $V_{OUT} = 2.5V/3A$



TYPICAL APPLICATION CIRCUITS (continued)

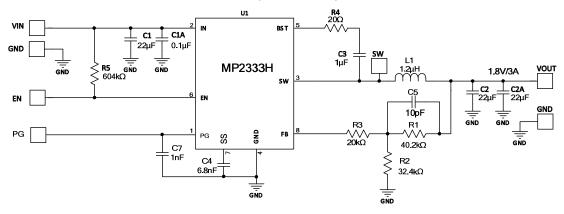


Figure 9: V_{IN} = 12V, V_{OUT} = 1.8V/3A

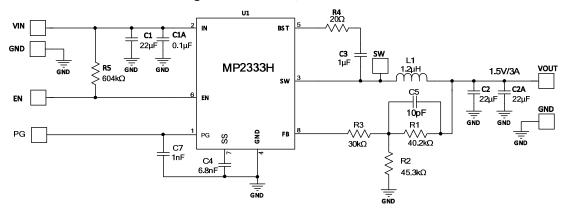


Figure 10: $V_{IN} = 12V$, $V_{OUT} = 1.5V/3A$

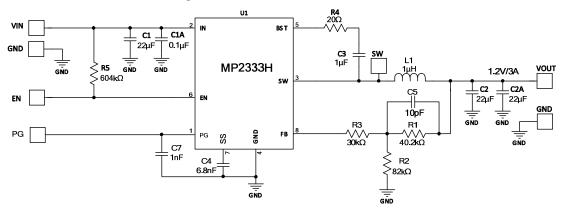


Figure 11: $V_{IN} = 12V$, $V_{OUT} = 1.2V/3A$



TYPICAL APPLICATION CIRCUITS (continued)

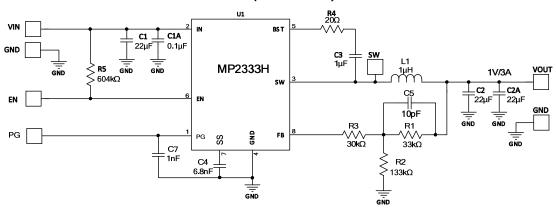
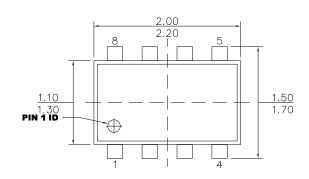


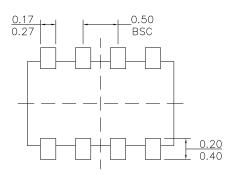
Figure 12: V_{IN} = 12V, V_{OUT} = 1V/3A



PACKAGE INFORMATION

SOT583 (1.6mmx2.1mm)



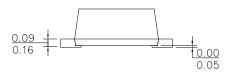


TOP VIEW

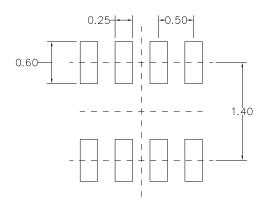
BOTTOM VIEW







SIDE VIEW



NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
3) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.10 MILLIMETERS MAX.
4) DRAWING IS NOT TO SCALE.

RECOMMENDED LAND PATTERN

NOTICE: The information in this document is subject to change without notice. Users should warrant and guarantee that third party Intellectual Property rights are not infringed upon when integrating MPS products into any application. MPS will not assume any legal responsibility for any said applications.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Switching Voltage Regulators category:

Click to view products by Monolithic Power Systems manufacturer:

Other Similar products are found below:

FAN53610AUC33X FAN53611AUC123X FAN48610BUC33X FAN48610BUC45X FAN48617UC50X R3 430464BB KE177614

MAX809TTR NCV891234MW50R2G NCP81103MNTXG NCP81203PMNTXG NCP81208MNTXG NCP81109GMNTXG

SCY1751FCCT1G NCP81109JMNTXG AP3409ADNTR-G1 NCP81241MNTXG LTM8064IY LT8315EFE#TRPBF NCV1077CSTBT3G

XCL207A123CR-G MPM54304GMN-0002 MPM54304GMN-0003 XDPE132G5CG000XUMA1 DA9121-B0V76 MP8757GL-P

MIC23356YFT-TR LD8116CGL HG2269M/TR OB2269 XD3526 U6215A U6215B U6620S LTC3803ES6#TR LTC3803ES6#TRM

LTC3412IFE LT1425IS MAX25203BATJA/VY+ MAX77874CEWM+ XC9236D08CER-G ISL95338IRTZ MP3416GJ-P BD9S201NUX-CE2 MP5461GC-Z MPQ4415AGQB-Z MPQ4590GS-Z MCP1603-330IMC MCP1642B-18IMC